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PATENT

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re application of:

Michelle D. Griglione

Serial No.: 10/598,213

Filed: August 21, 2006

For: A BIPOLAR JUNCTION TRANSISTOR HAVING A HIGH  
GERMANIUM CONCENTRATION IN A SILICON-  
GERMANIUM LAYER AND A METHOD FOR FORMING THE  
BIPOLAR JUNCTION TRANSISTOR

Group No.: 2893

Examiner: Benjamin T. Liu

Confirmation No.: 1211

Commissioner for Patents  
P.O. Box 1450  
Alexandria, VA 22313-1450

I hereby certify that this correspondence is being electronically filed  
with United States Patent and trademark Office on:  
August 25, 2008 (Date)

Elizabeth Schumacher  
(Printed or typed name of person signing the certificate)

/Elizabeth Schumacher/  
(Signature of the person signing the certificate)

Sir:

ELECTION OF CLAIMS

In response to the Official Action of July 29, 2008, Applicant hereby elects, without traverse,  
Claims 19- 33, comprising Group II listed below: